



●Pin Configuration

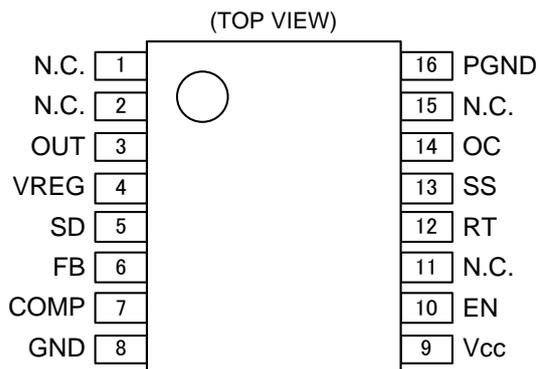


Figure 2. Pin Configuration

●Pin Description

Pin No.	Pin Name	Function
1	N.C.	Not connected
2	N.C.	Not connected
3	OUT	Gate driver output pin
4	VREG	Regulator output for FET driver pin
5	SD	Transistor driver pin for shutdown
6	FB	Error amplifier inverted input pin
7	COMP	Error amplifier output pin
8	GND	Ground pin
9	Vcc	Power supply pin
10	EN	EN functionality pin
11	N.C.	Not connected
12	RT	Frequency setting pin
13	SS	Soft start setting pin
14	OC	Overcurrent detection pin
15	N.C.	Not connected
16	PGND	Power ground pin

•Block Diagram

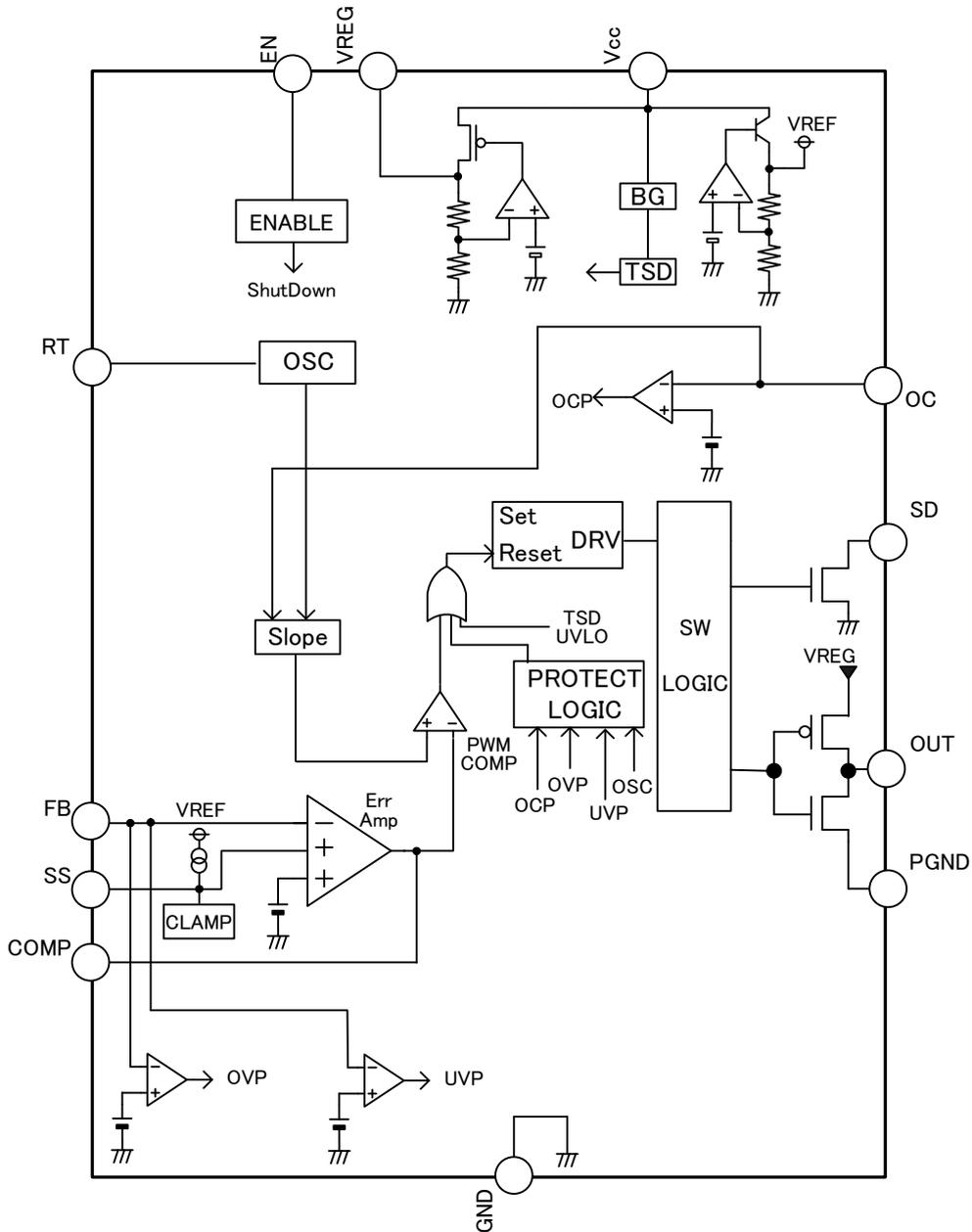


Figure 3. Block Diagram

**•Explanation of Block Operations**

- VREF  
3.0V Regulator block for internal supply.
- VREG  
Voltage supply block for DC/DC driver.
- TSD  
Thermal protection block that turns off the IC if the internal temperature reaches 175°C (typ.).
- UVLO  
Undervoltage-lockout block.
- OVP  
Overvoltage protection block that turns off the IC if FB exceeds 0.92V (typ.).  
If the protection function is activated, the output is turned off and the Soft Start pin and COMP pin voltages are discharged for a fixed period dependent on the oscillation frequency.
- UVP  
Undervoltage protection block that turns off the IC if FB drops below 0.60V (typ.).  
If the protection function is activated, the output is turned off and the Soft Start pin and COMP pin voltages are discharged for a fixed period dependent on the oscillation frequency.
- Error amplifier (ERR)  
Block that compares the output feedback voltage to the reference voltage and outputs the difference to the COMP pin, which voltage is used to determine the switching duty cycle.
- Oscillator (OSC)  
Block that generates the oscillation frequency.
- Slope  
Block that generates a triangle wave from the clock generated in the oscillator block and sends it to the PWM comparator.
- PWM  
Block that compares the output COMP pin voltage of the error amplifier with the triangle wave of the slope and determines the switching duty. The switching duty is limited by the internally set maximum duty ratio and cannot become 100%.
- DRV  
DC/DC driver block with the PWM signal as input and that drives the output MOS.
- Soft start  
Block that limits the current at time of startup and gradually increases the output voltage thereby preventing an overshoot of the output voltage and inrush current.
- OCP  
Overcurrent protection block. The overcurrent protection level is determined by the value of the resistor placed in between the OC pin and GND. Overcurrent is detected when the OC pin voltage exceeds 0.2V (typ.). The overcurrent detection function is performed every switching pulse cycle. When overcurrent is detected 256 times consecutively, the overcurrent protection is activated and the IC is shut down. Thus, even if the OC pin reaches or exceeds the overcurrent detection level caused by a DC voltage, the overcurrent protection is not activated since it is only a one time detection.  
If the protection function is activated the output is turned and the Soft Start pin and COMP pin are discharged for a fixed period depending on the oscillator frequency.
- SD  
Transistor driver block for turning off the IC when a protection function is activated (Nch open drain).

**•Absolute Maximum Ratings (Ta=25°C)**

Parameter	Symbol	Rating	Unit
Voltage	Vcc	-0.3 to 35* <sup>1</sup>	V
VREG Voltage	VREG	7	V
EN Voltage	VEN	Vcc	V
OC Voltage	VOC	V <sub>REG</sub>	V
SD Voltage	VSD	Vcc	V
Power Dissipation	Pd	870* <sup>2</sup>	mW
Operating Temperature Range	Top	-40 to +125	°C
Storage Temperature Range	Tstg	-55 to +150	°C
Junction Temperature	Tjmax	150	°C

\*1 Pd should not be exceeded.

\*2 7.0mW/°C reduction when Ta ≥ 25°C if mounted on a glass epoxy board of 70mm×70mm×1.6mm

**•Operating Conditions (Ta=-40°C to +125°C)**

Parameter	Symbol	Rating			Unit
		Min.	Typ.	Max.	
Voltage	Vcc	4.5	14	30	V
Oscillation frequency	FOSC	20	—	600	kHz

### ●Electrical Characteristics

(Unless otherwise specified:  $4.5 \leq V_{CC} \leq 30V$ ,  $-40^{\circ}C \leq T_{op} \leq 125^{\circ}C$ , current flowing from the IC is defined +)

Parameter	Symbol	Ratings			Unit	Conditions
		Min.	Typ.	Max.		
<b>Output block</b>						
Output voltage H1	VOUTH1	4.5	5.0	5.5	V	$5 \leq V_{CC} \leq 30V$ IOU=0A(open)
Output voltage H2	VOUTH2	4.0	4.5	-	V	$V_{CC}=4.5V$ IOU=0A(open)
Output voltage L	VOU <sub>L</sub>	0	-	0.3	V	IOU=0A(open)
MOS on resistor (source)	Ron_source	3	6	12	$\Omega$	Isource=10mA
MOS on resistor (sink)	Ron_sink	0.46	0.84	1.80	$\Omega$	Isink=-10mA
<b>Oscillator block</b>						
Oscillation frequency	fsw	360	400	440	kHz	RT=72k $\Omega$
<b>Soft start block</b>						
Output range	VSSout	1.8	2.2	2.6	V	
Startup charge current	Istr	7.5	10.0	12.5	$\mu A$	SS=0V
Shut-off discharge current	Istp	-8.0	-3.0	-0.6	mA	
<b>Error amp. block</b>						
Threshold voltage	Veth	0.788	0.800	0.812	V	FB=COMP
Input bias current	IIB	-1	-	1	$\mu A$	FB=1.0V
Output sink current	Icompsink	-150	-75	-20	$\mu A$	FB=1.0V COMP=0.8V
Output source current	Icompsource	20	75	150	$\mu A$	FB=0.6V COMP=0.8V
<b>EN block</b>						
Threshold voltage	VEN	1.00	2.15	2.70	V	
Input bias current	IEN	8	16	32	$\mu A$	EN=3V
<b>UVLO block</b>						
UVLO operating voltage	VUVLO	3.3	3.6	3.9	V	VREG SWEEP DOWN
Hysteresis voltage	VULO <sub>hys</sub>	200	400	600	mV	VREG SWEEP UP
<b>Overvoltage protection block</b>						
Overvoltage detection threshold	Vovth	0.90	0.92	0.94	V	
<b>FB open detection block</b>						
Undervoltage detection threshold	Vopth	0.57	0.60	0.63	V	
<b>Overcurrent protection block</b>						
Overcurrent detection threshold	Vocth	0.16	0.20	0.24	V	
<b>Hibernation period adjustment block</b>						
Max on DUTY	Donmax	77	87	97	%	
<b>Transistor driver block for shutdown</b>						
Pin voltage (normal operation)	Vsdl	0	-	0.8	V	Normally "L" Isdsink=-1mA
Leakage current	Isdleak	-	-	10	$\mu A$	Vsd=30V
<b>Entire chip</b>						
Average current consumption	ICC	-	3	6	mA	Switching off

○This product is not designed to be radiation resistant.

• Characteristics Data (reference data)

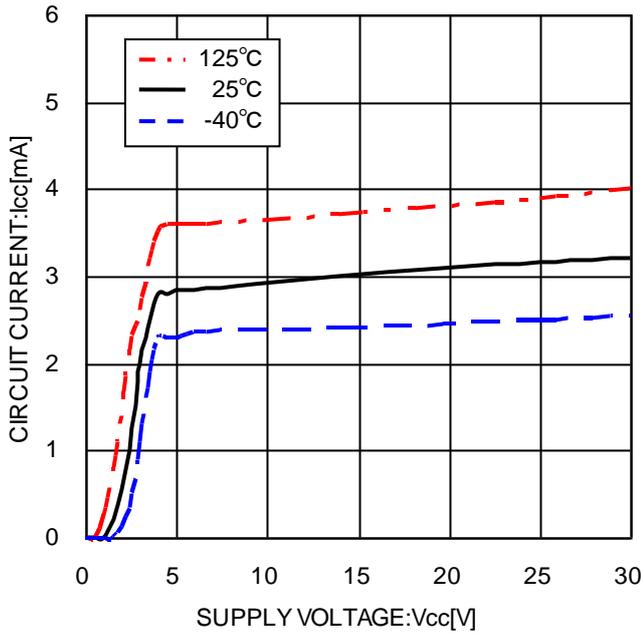


Figure 4. Average current consumption

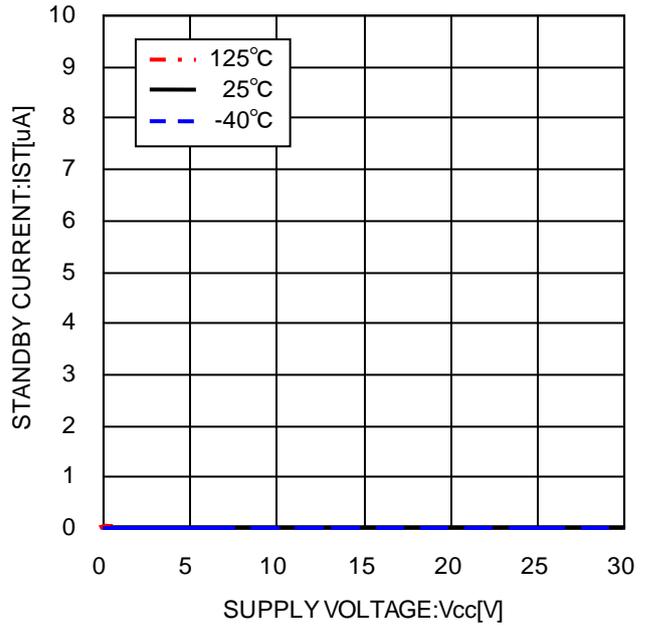


Figure 5. Standby current

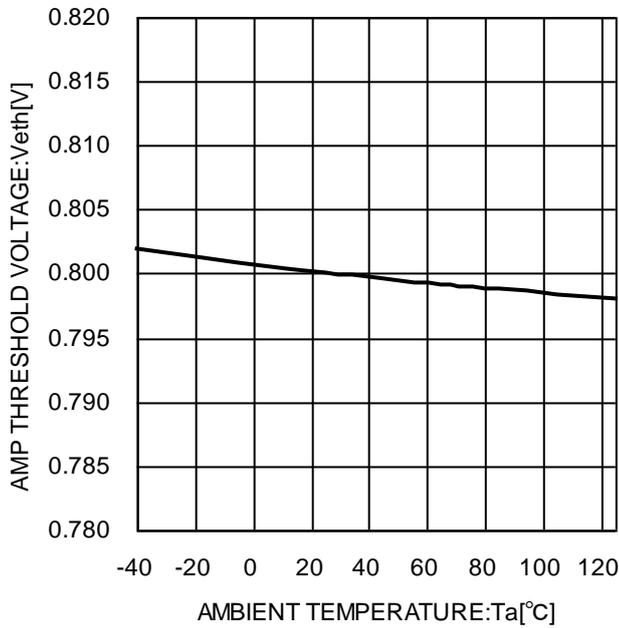


Figure 6. Error amp threshold voltage vs. temperature characteristics

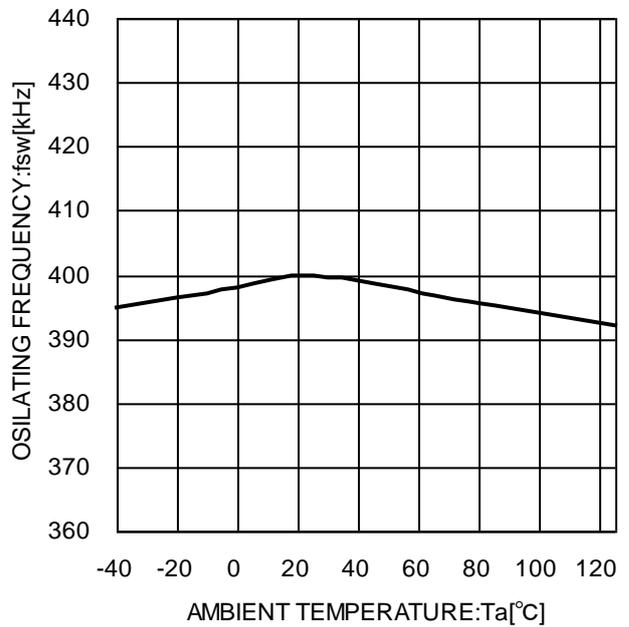


Figure 7. Oscillation frequency vs. temperature characteristics

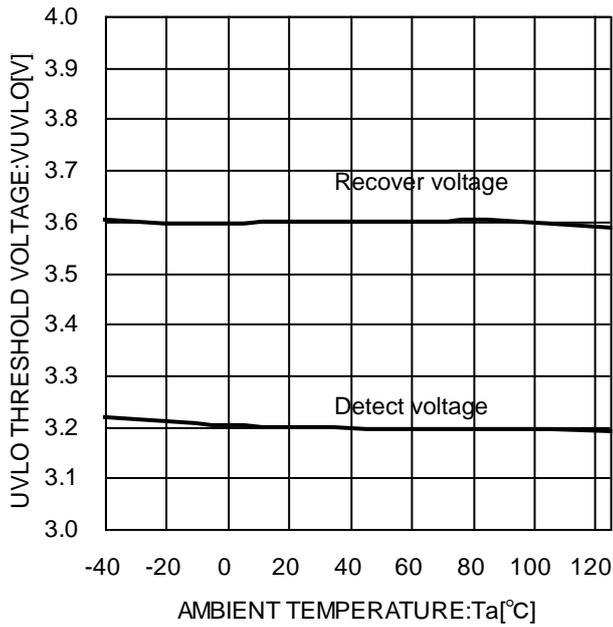


Figure 8. UVLO operating/return voltage vs. temperature characteristics

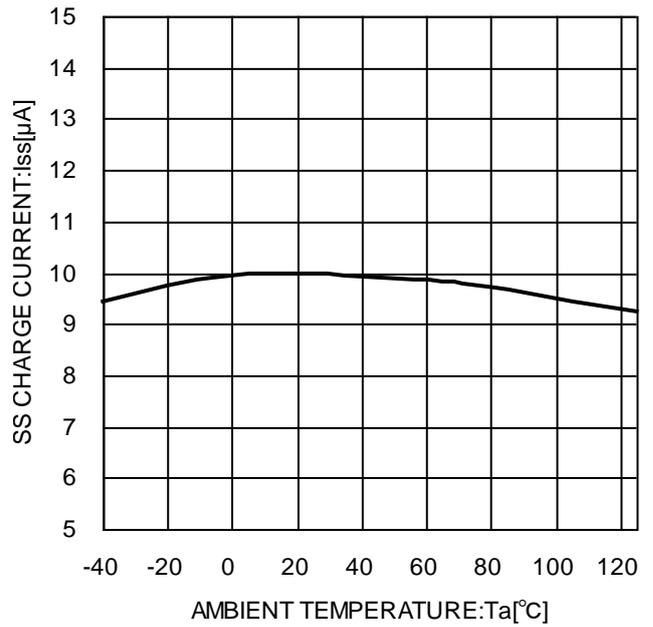


Figure 9. Soft start startup charge vs. temperature characteristics

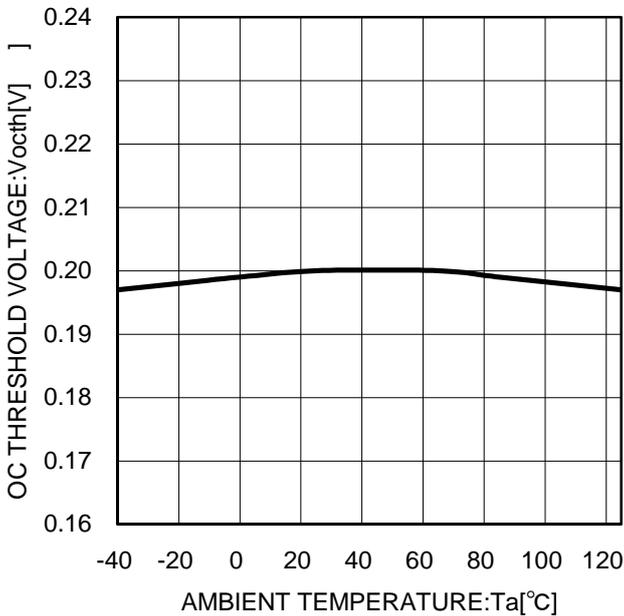


Figure 10. Overcurrent threshold voltage vs. temperature characteristics

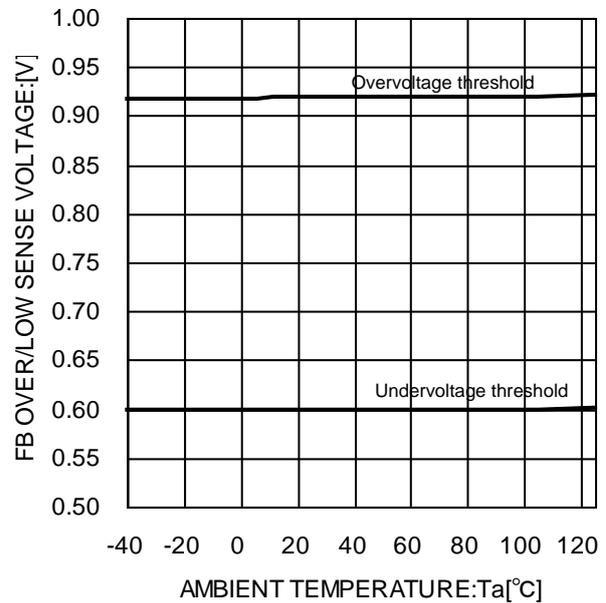


Figure 11. FB pin overvoltage/undervoltage threshold voltage vs. temperature characteristics

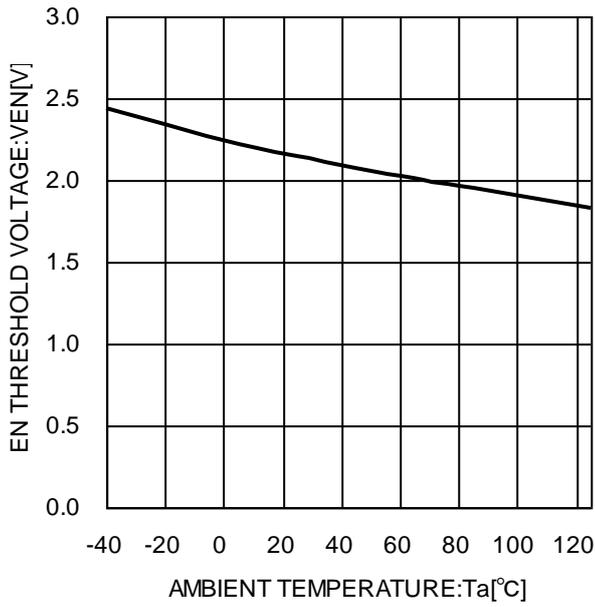


Figure 12. EN threshold voltage vs. temperature characteristics

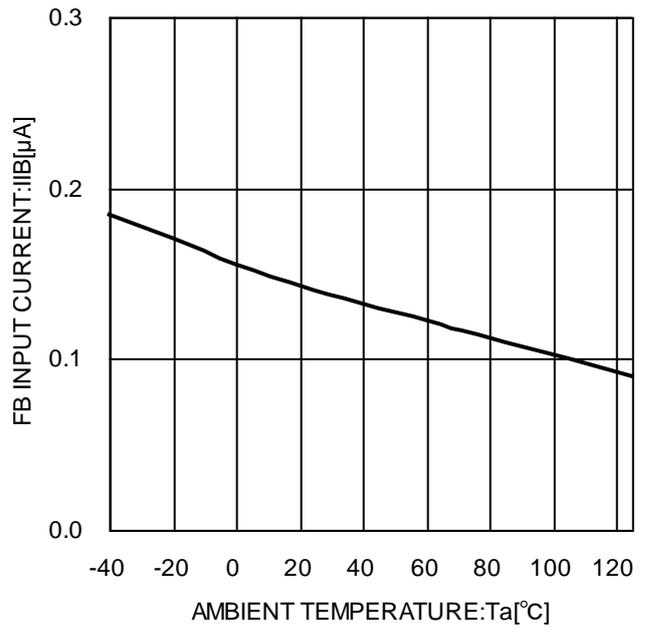


Figure 13. FB pin input bias current vs. temperature characteristics

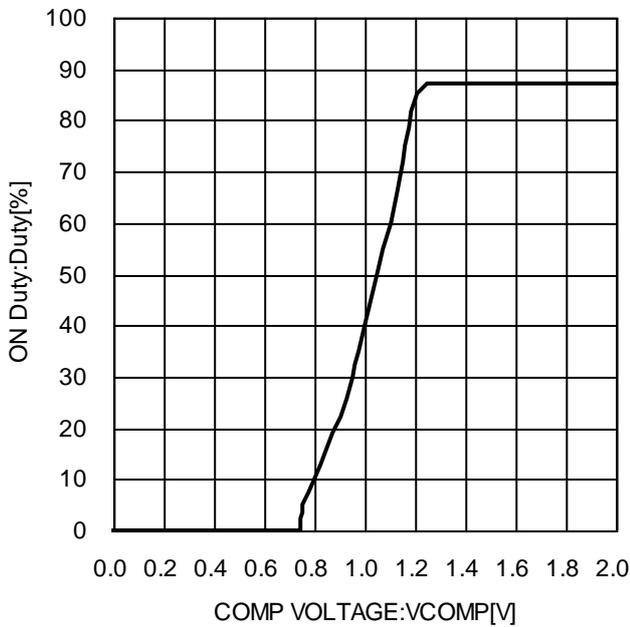


Figure 14. ON Duty characteristics

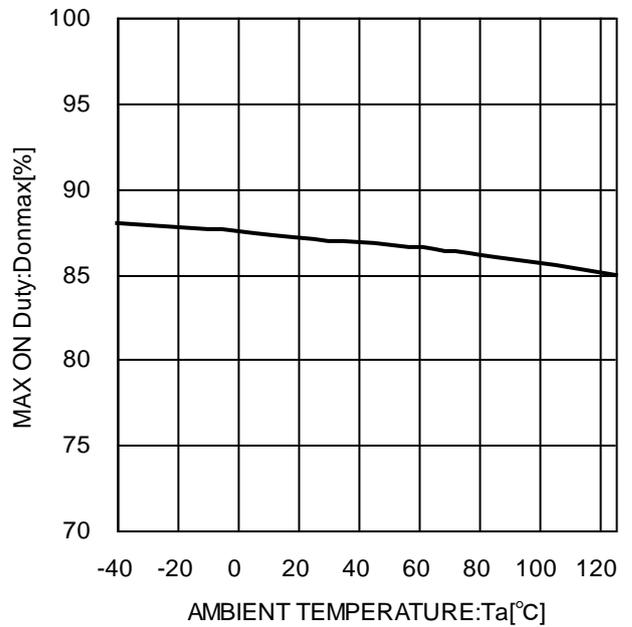


Figure 15. Max. ON duty vs. temperature characteristics

●Timing chart

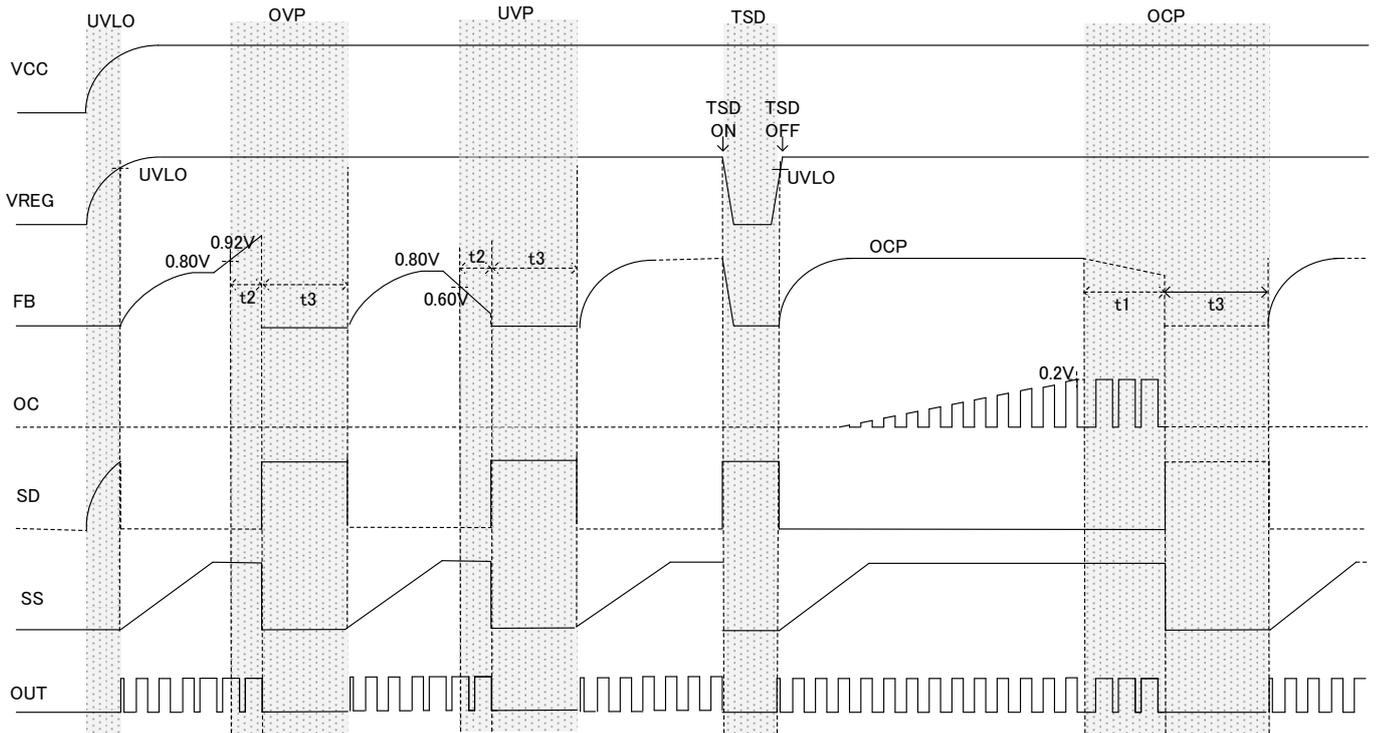


Figure 16. Timing chart

■Detection Time

The IC will be shut down if the time resulting from the following equation is exceeded.

After OCP detection,  $t1 = 1/f \times 256clk$  (s)

Time needed for the OC pin output pulse to synchronize with the switching frequency and for the OCP block to perform 256 consecutive detections.

After OVP or UVP detection:  $t2 = 1/f \times 4clk$  (s)

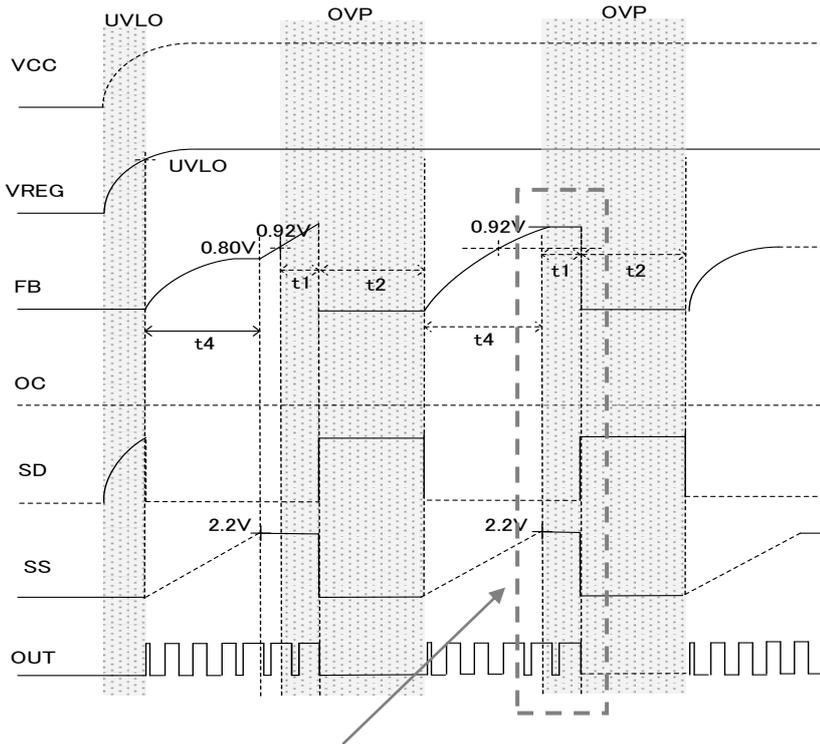
■Release Time

The output is turned off and the Soft start and COMP voltages are discharged during the time resulting from the following equation.

OVP or UVP or OCP,  $t3 = 1/f \times 1024clk$  (s)

f: Oscillator frequency (kHz)

•Overvoltage Protection (OVP) Timing chart



This chart shows the overvoltage detection start time after startup. This start time can be calculated as follows:

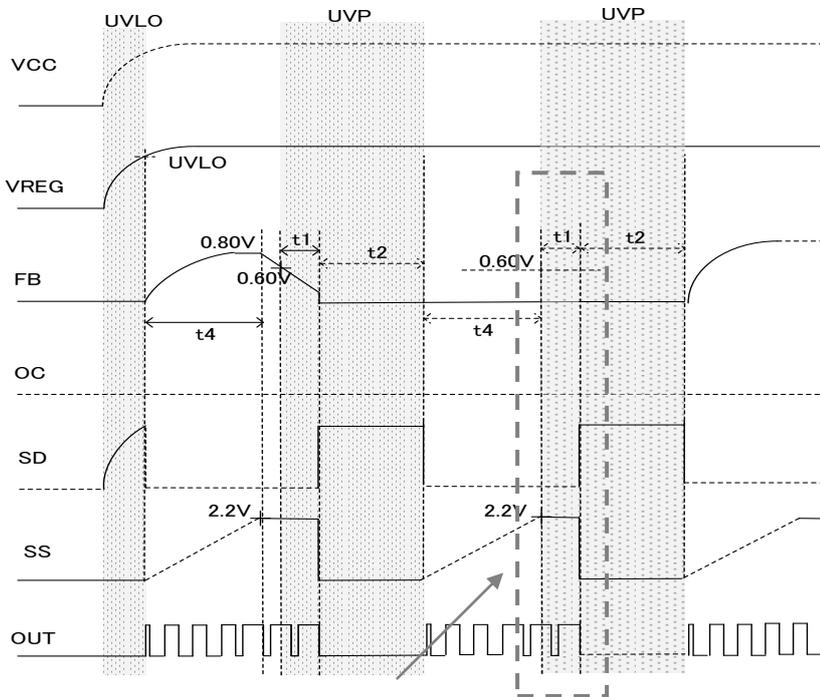
$$t4 = 2.2V \text{ (typ.)} \times C_{SS} / 10\mu A \text{ (typ.)} \text{ (s)}$$

2.2V (typ.): soft start output range  
 C<sub>SS</sub>: SS pin external capacitor  
 10μA (typ.): soft start charge current

The Over-voltage is detected after the soft start voltage reaches 2.2V (typ.).

Figure 17. Overvoltage protection (OVP) timing chart

•Undervoltage Protection (UVP) Timing chart



This chart shows the Undervoltage detection start time after startup. This start time can be calculated as follows:

$$t4 = 2.2V \text{ (typ.)} \times C_{SS} / 10\mu A \text{ (typ.)} \text{ (s)}$$

2.2V (typ.): soft start output range  
 C<sub>SS</sub>: SS pin external capacitor  
 10μA (typ.): soft start charge current

Under-voltage is detected after the soft start voltage reaches 2.2V (typ.).

Figure 18. Undervoltage protection (UVP) timing chart

•Reference data  
Non-isolated type application

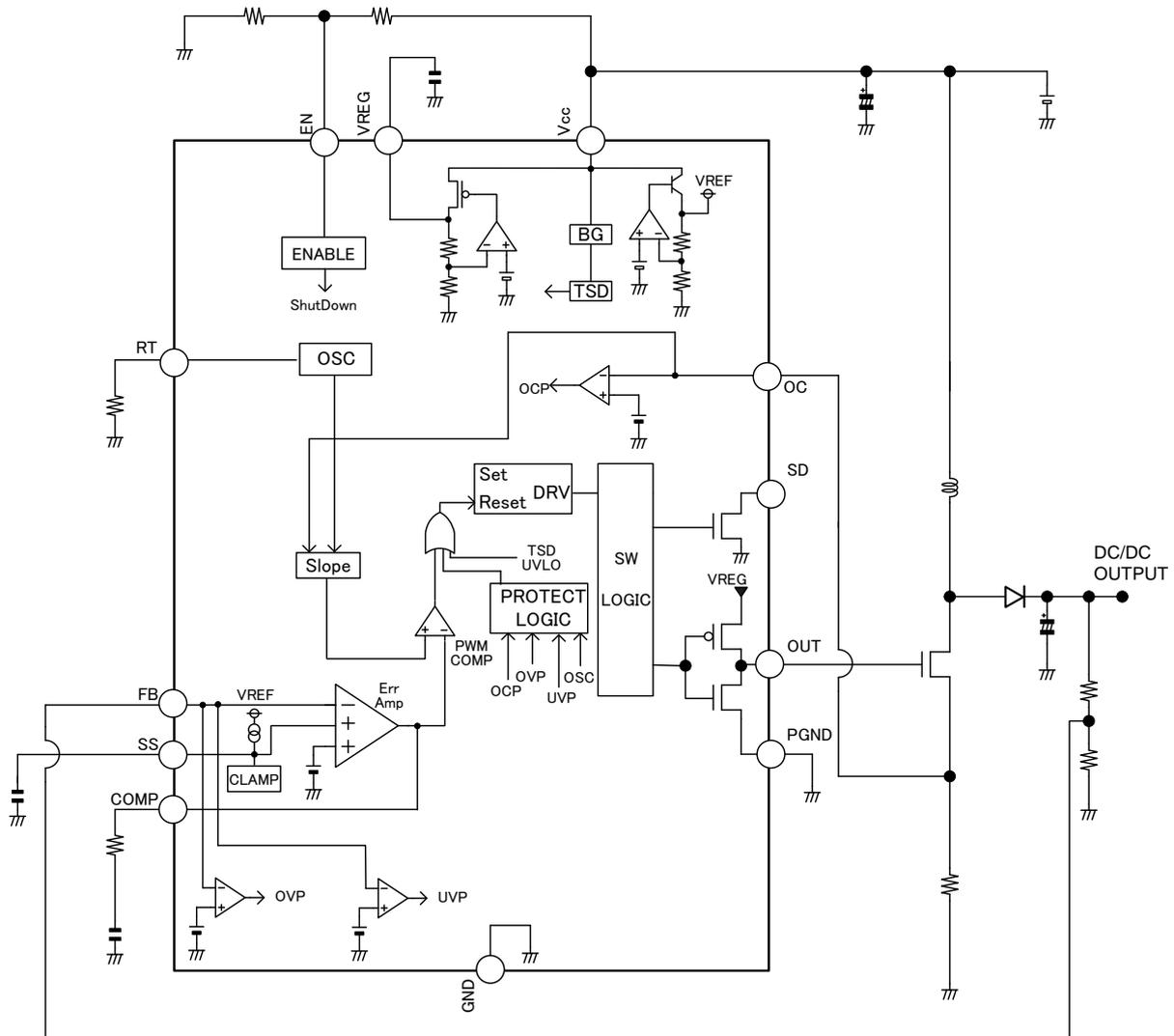


Figure 19. Non-isolated type application circuit example

Flyback type application

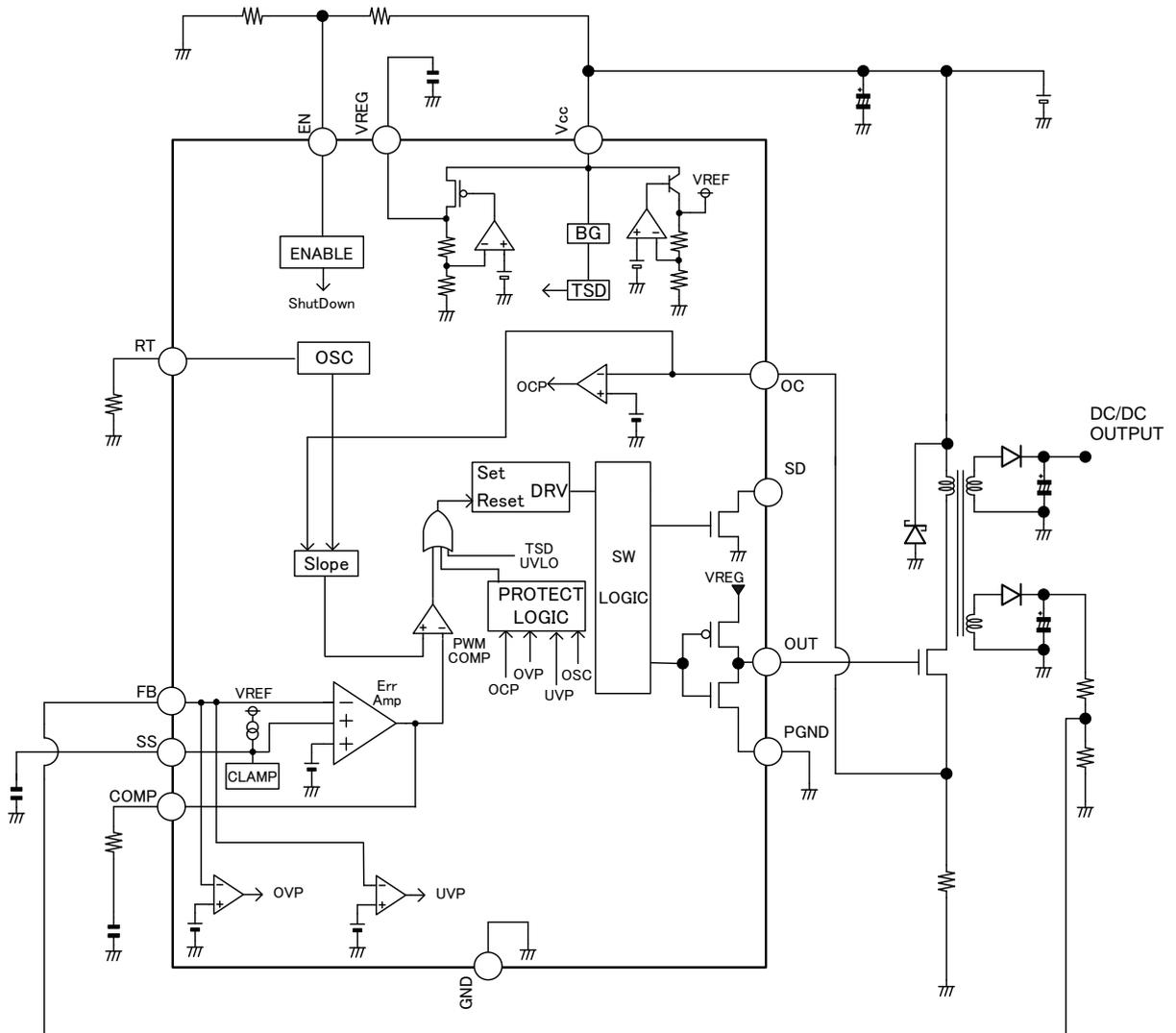


Figure 20. Flyback type application circuit example

Non-isolated application using SD

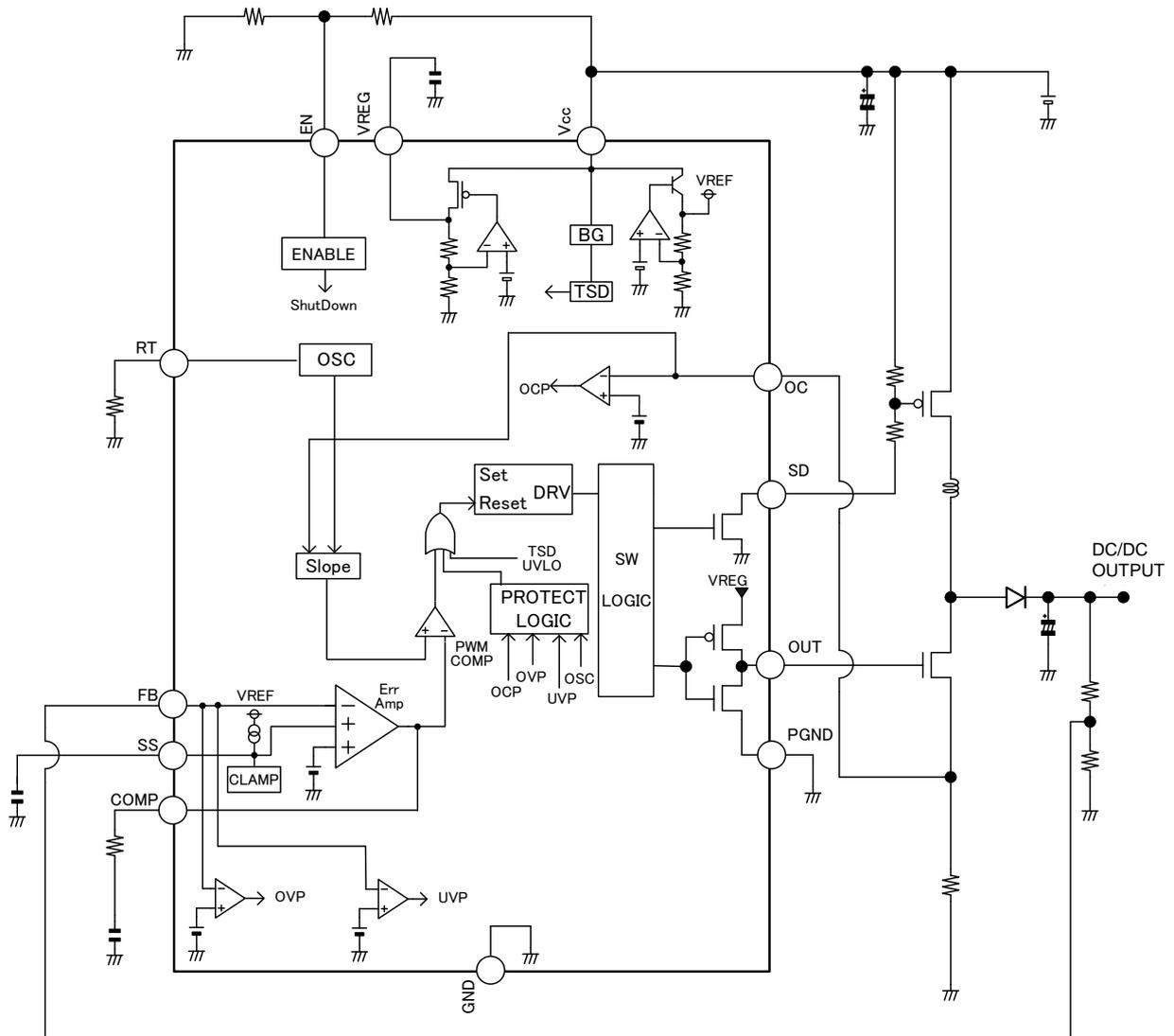


Figure 21. Non-isolated application using SD circuit example

There are many factors (e.g.PCB layout, external parts, etc.) that can affect the characteristics. Therefore, please validate and confirm performance and functionality using actual applications.

● Selection of External Components

(1) Setting the output L value (step-up DC/DC)

Though a coil is used for the following explanation, a transformer can also be used for the same explanation. The rated current (ILR) of the output coil (L) is determined by the maximum input current IINMAX

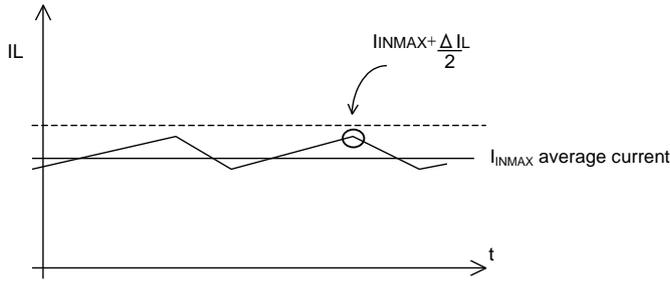


Figure 22. Coil current waveform (step-up DC/DC)

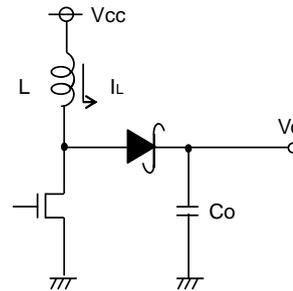


Figure 23. Output application circuit example (step-up DC/DC)

Please ensure that IINMAX + ΔIL / 2 does not reach the rated current ILR. In this case ΔIL can be calculated using the formula below.

$$\Delta IL = \frac{1}{L} V_{cc} \times \frac{V_o - V_{cc}}{V_o} \times \frac{1}{f} \quad (A) \quad f: \text{switching frequency}$$

Also, coil L has a variation of about 30% so please allow for a sufficient margin. If the coil current exceeds the coil rated current ILR, this might lead to damages to the IC internal components.

(2) Setting the output capacitor

Select the output capacitor considering the acceptable ripple voltage (Vpp). The following equation is used to determine the output ripple voltage.

$$\Delta V_{PP} = I_{LMAX} \times R_{ESR} + \frac{1}{f C_o} \times \frac{V_{cc}}{V_o} \times \left( I_{LMAX} - \frac{\Delta IL}{2} \right) \quad (V) \quad (\text{step-up DC/DC})$$

(3) Setting the input capacitor

The input capacitor serves to lower the output impedance of the power source connected to the input pin. Increased power supply output impedance can cause input voltage instability and may negatively impact oscillation and ripple rejection characteristics. Therefore, it is necessary to place an input capacitor in close proximity to the Vcc and GND pins.

A low-ESR capacitor with a value between 10μF and 100mΩ is recommended. Selecting a capacitor with a value outside of the recommended range will lead to an excessive ripple voltage being superimposed on the input voltage and may cause the IC to malfunction.

Also, be certain to ascertain the operating temperature, load range and MOSFET conditions for the application in which the capacitor will be used, since capacitor performance is heavily dependent on the application's input power characteristics, substrate wiring and MOSFET gate drain capacity

(4) Setting the output voltage

The output voltage is determined by the equation below. Select a combination of R1 and R2 to obtain the required voltage.

Note that a small resistance value leads to a drop in power efficiency and that a large resistance value leads, due to the error amp output drain current of 0.13μA (typ.), to an increase of the offset voltage

$$V_{out} = 0.8 \times \frac{R1 + R2}{R2}$$

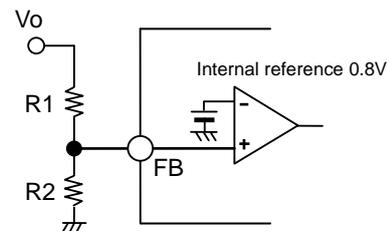


Figure 22. Output voltage setting circuit diagram

(5) Setting the oscillation frequency

The internal oscillation frequency is determined by the resistance value connected to RT.

The setting range is 20kHz to 600kHz. The correlation between the resistance value and the oscillation frequency is as shown in figure 23. A setting outside of the range shown below may cause the switching to stop after which operation is no longer guaranteed.

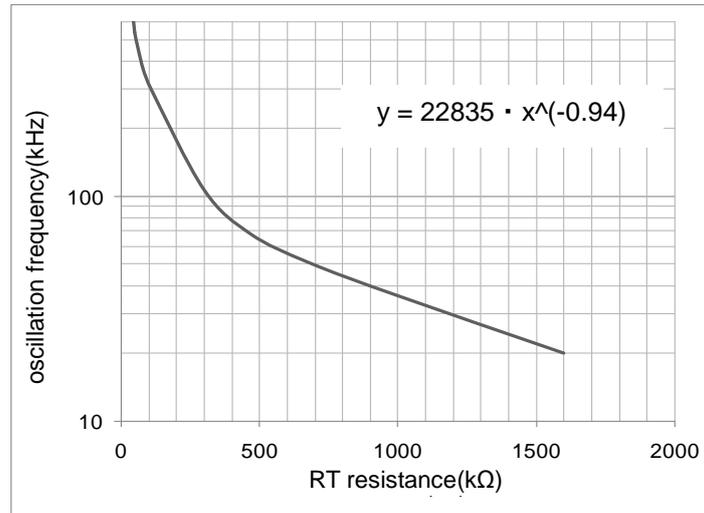


Figure 23. RT resistance vs. oscillation frequency

(6) Soft start delay time

In order to limit the current during startup the soft start pin needs to be connected to a capacitor. By connecting the capacitor output voltage overshoots and inrush currents can be prevented.

The delay time is dependent on the capacitor value connected to the soft start pin and can be calculated using the formula below. (We recommend a capacitor with a value in the range of 0.01 to 0.47μF.)

$$T_{ss} \text{ (typ.)} = (C_{ss} \times 0.8\text{V (typ.)}) / 10\mu\text{A (typ.)} \text{ (s)} \quad (C_{ss}: \text{Soft Start pin external capacitor})$$

Note 0.8V: Initial soft start voltage that Vo outputs  
10μA: Soft start charge current

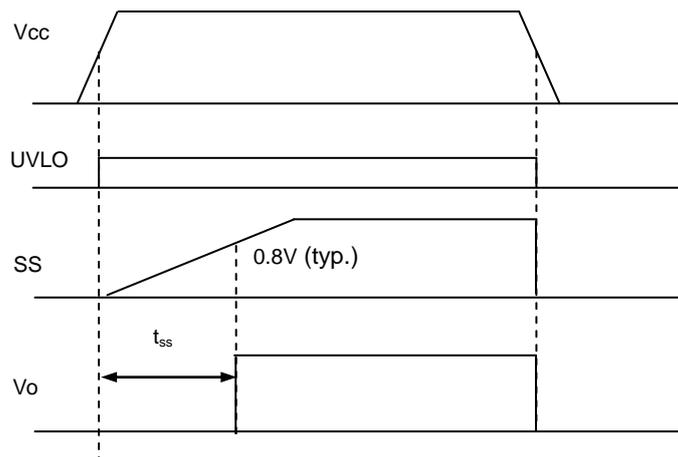


Figure 24. Soft start operating timing chart

(7) Overcurrent protection

The overcurrent protection value is determined by the resistance (Roc) connected between OC and GND and the OC pin

voltage and can be calculated by using the formula below.

$$R_{oc} \times I_o > V_{octh} \quad \text{※} V_{octh} = \text{voltage between OC and GND}$$

e.g.) Setting the overcurrent protection at 2A

$$R_{oc} \times 2A = V_{octh}$$

$$R_{oc} = \frac{V_{octh}}{2A}$$

Based on that the overcurrent detection threshold =0.2V (typ.)

$$R_{oc} = \frac{0.2}{2A} = 0.1\Omega$$

(3) Setting the phase compensation circuit

Negative feedback stability conditions are as follows:

- At time of unity gain (0dB) the phase delay should be 135° or less. (i.e. the phase margin is 45° or higher)
- As the DC/DC converter application is sampled according to the switching frequency, GBW (frequency at 0-dB gain) of the overall system should be set to 1/10 or less of the switching frequency.

Thus, as the response is determined by the limitation of  $f_c$  (GBW), it is necessary to increase the switching frequency in order to raise the response.

The phase compensation is set by the capacitors and resistors serially connected to the COMP pin. Achieving stability by using the phase compensation is done by cancelling the 2 poles (error amp pole and power stage pole) of the regulation loop by use of  $f_{z1}$ .

$$f_{p1} = \frac{G_{EA}}{2\pi \times C_1 \times A_{VE}}$$

$$f_{p2} = \frac{1}{2\pi \times C_0 \times R_{LOAD}}$$

$$f_z = \frac{1}{2\pi \times C_1 \times R_1}$$

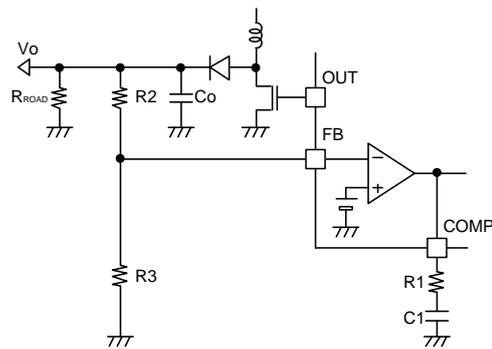
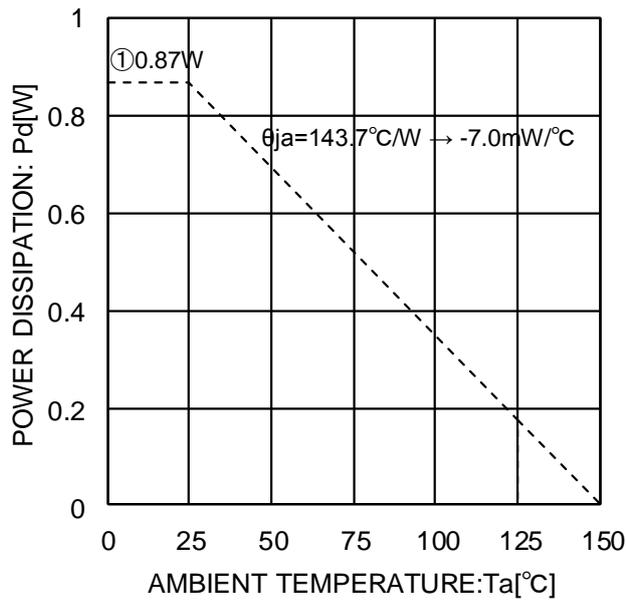


Figure 25. Phase compensation application circuit example

In the formula above,  $G_{EA}$  is the error amp transconductance (400 $\mu$ A/V) and  $A_{VE}$  is the error amp voltage gain (200V/V). This setting is obtained by using a simplified calculation, therefore, adjustment on the actual application may be required. Also as these characteristics are influenced by the substrate layout, load conditions, etc. verification and confirmation with the actual application at time of mass production design is recommended.

●Heat dissipation

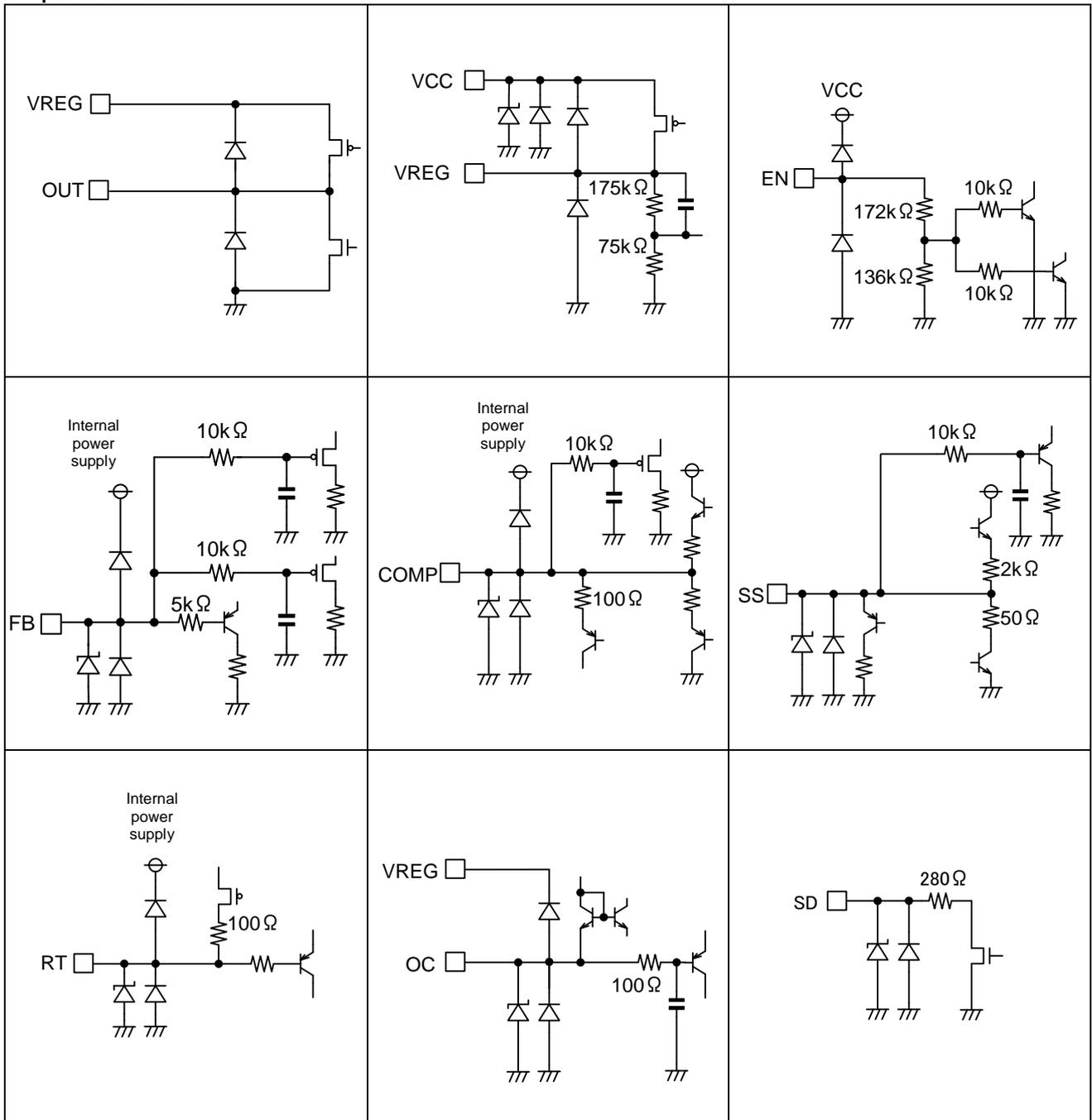


① IC mounted on a ROHM standard board (70mm × 70mm × 1.6mm glass epoxy board)

Figure 26. SSOP-B16 Power dissipation heat attenuation characteristics

Figure 26. shows the power dissipation and heat attenuation characteristics of the SSOP-B16 package. Even if the ambient temperature Ta is at room temperature (25°C), it can be that the chip (juncture) temperature becomes very high. Therefore, please be sure to operate the IC within the power dissipation range.

• I/O equivalence circuits



**•Operational Notes**

- 1) Absolute maximum ratings  
Exceeding the absolute maximum rating for supply voltage, operating temperature or other parameters, can result in destruction of the chip. In this event it also becomes impossible to determine the cause of the damage (e.g. short circuit, open circuit, etc). Therefore, if any special mode is being considered with values expected to exceed the absolute maximum ratings, implementing physical safety measures, such as adding fuses, should be considered.
- 2) Electrical characteristics  
The electrical characteristics given in this specification may be influenced by conditions such as temperature, supply voltage and external components. Transient characteristics should be sufficiently verified.
- 3) GND electric potential  
Keep the GND terminal potential at the lowest (minimum) potential under any operating condition. Furthermore, excluding the GND pin, the voltages of all pins should never drop below that of GND.
- 4) GND wiring pattern  
When both a small-signal GND and a high current GND are present, single-point grounding (at the set standard point) is recommended. This must be done in order to separate the small-signal and high current paths and to ensure that voltage changes stemming from the wiring resistance and high current do not cause any voltage change in the small-signal GND. Similarly, care must be taken to avoid any changes in the ground paths of externally connected components.
- 5) Inter-pin shorting and mounting errors  
Ensure that when mounting the IC on the PCB the direction and position are correct. Incorrect mounting may result in damaging the IC. Also, shorts caused by dust entering between the output, input and GND pin may result in damaging the IC.  
Note: the overcurrent protection is not activated when the drain-source pin of the external FET is shorted.
- 6) Operation in strong electromagnetic fields  
Use caution when operating in the presence of strong electromagnetic fields, as this may cause the IC to malfunction.
- 7) Testing on application boards  
The IC needs to be discharged after each test process. Because when using an application board for testing, connecting a capacitor to a low-impedance pin may cause stress to the IC. As a protection from static electricity, ensure that the assembly setup is grounded and take sufficient caution with transportation and storage. Also, make sure to turn off the power supply when connecting and disconnecting the inspection equipment.
- 8) Power dissipation  
Should, by any chance, the power dissipation rating be exceeded, the rise in temperature of the chip may result in deterioration of the properties of the chip. The power dissipation value noted in this specification under absolute maximum ratings is the value in case of a 70mm×70mm×1.6mm glass epoxy board. In case this value is exceeded please take appropriate measures such as increasing the board size.
- 9) Thermal design  
The power dissipation under actual operating conditions should be taken into consideration and a sufficient margin should be allowed for in the thermal design.
- 10) Vcc pin  
Please be sure to insert a capacitor between Vcc and GND. Select the value of the capacitor based on the line of the power smoothing circuit and input pin (Vcc). The capacitance setting may vary according to the application. Therefore its value should be verified in actual application with a sufficient margin in place. It is recommended to use a capacitor with good voltage and temperature characteristics.
- 11) Capacitor connected to the VREG pin  
In order to prevent oscillation, a capacitor needs to be placed between the output pin and GND pin. It is recommended to use a capacitor with a capacitance of 4.7μF or higher. Electrolytic, tantalum and ceramic capacitors can be used. When selecting the capacitor ensure that the capacitance of 4.7μF or higher is maintained at the intended applied voltage and temperature range. Due to changes in temperature the capacitor's capacitance can fluctuate possibly resulting in oscillation.  
When selecting a ceramic type capacitor, we recommend using X5R, X7R or better with excellent temperature and DC-biasing characteristics and high voltage tolerance.  
Also, in case of rapidly changing input voltage and load current, select the capacitance in accordance with verifying that the actual application meets with the required specification.
- 12) EN pin  
In case of connecting a resistor to the EN pin, as shown in figures 19 to 21, please ensure a setting in which the EN pin voltage is higher than the ON voltage (2.7V).

13) SD pin

In case of using a SD pin, as shown in figure 21., please sufficiently consider the operating voltage of the external PchMOS when setting the resistance value.

14) Thermal shutdown (TSD)

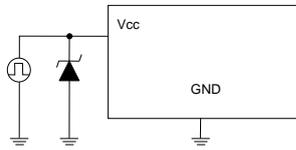
This IC incorporates an integrated thermal shutdown circuit to prevent heat damage to the IC. Normal operation should be within the power dissipation rating, if however the rating is exceeded for a continued period, the junction temperature ( $T_j$ ) will rise and the TSD circuit will be activated and turn all output pins OFF. After the  $T_j$  falls below the TSD threshold the circuits are automatically restored to normal operation.

Note that the TSD circuit operates in a situation that exceeds the absolute maximum ratings and therefore, under no circumstances, should the TSD circuit be used in a set design or for any purpose other than protecting the IC from heat damage.

15) Based on the application the Vcc and other pin voltages might be reversed, possibly resulting in circuit internal damage or damage to components. For example, while the external capacitor is charged, Vcc shorts to GND. Using reverse polarity diodes in series or a bypass diode between all pins and the Vcc pin is therefore recommended.

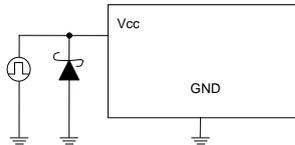
16) Applying a positive surge to the Vcc pin

In case surges exceeding 35V will be applied to the Vcc pin, please place a power zener diode between Vcc and GND as shown in the figure below.



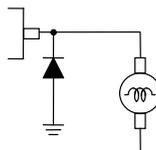
17) Applying a negative surge to the Vcc pin

If the possibility exists that the Vcc voltage will be lower than that of the GND pin, please place a Shottky diode between Vcc and GND as shown in the figure below.



18) Placing a protection diode

If the possibility exists that a large inductive load is connected to the output pin resulting in back-EMF at time of startup and shutdown, a protection diode should be placed as shown in the figure below.

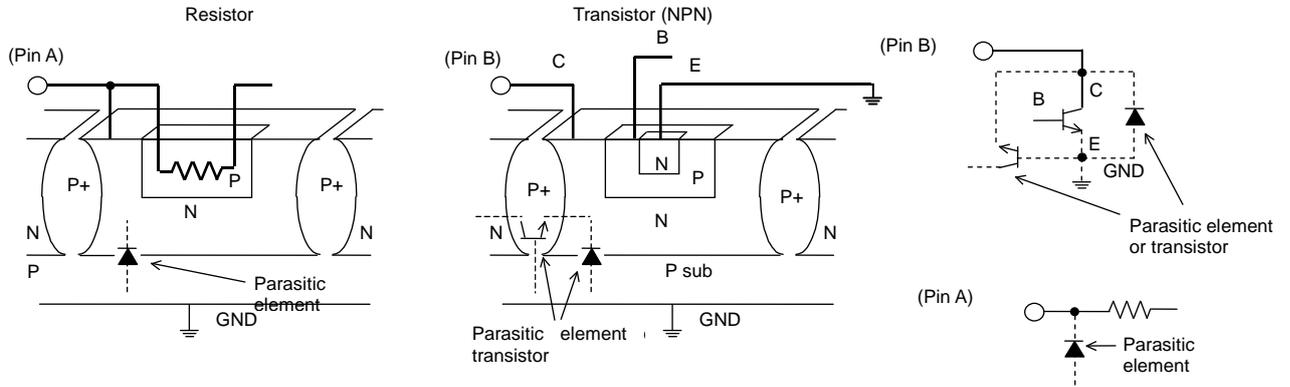


19) This monolithic IC contains P+ isolation and P substrate layers between adjacent elements in order to keep them isolated. P/N junctions are formed at the intersection of these P layers with the N layers of other elements to create a variety of parasitic elements.

For example, in case a resistor and a transistor are connected to the pins as shown in the figure below then:

- The P/N junction functions as a parasitic diode when GND > pin A for the resistor, or GND > pin B for the transistor.
- Also, when GND > pin B for the transistor (NPN), the parasitic diode described above combines with the N layer of the other adjacent elements to operate as a parasitic NPN transistor.

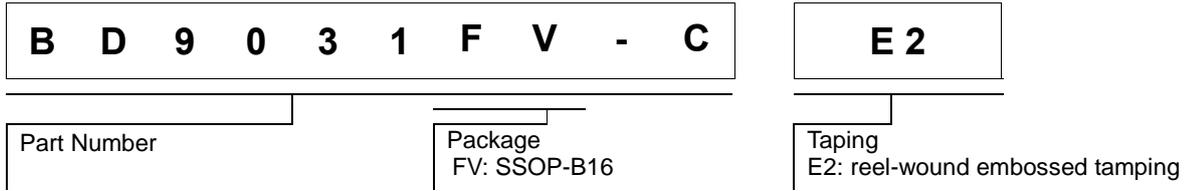
Parasitic diodes inevitably occur in the structure of the IC. Their influence can result in mutual interference between circuits and can cause malfunctions and, in turn, physical damage to or destruction of the chip. Therefore, the input pin voltage should not be lower than the (P substrate) GND in order to prevent the parasitic diodes to conduct.



Note concerning this document

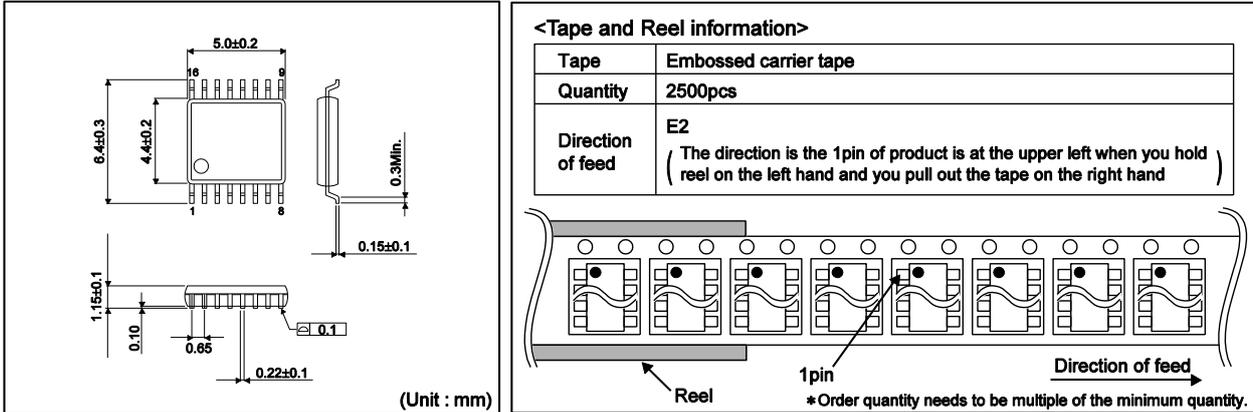
The Japanese version of this document is the official specification. This translation should be seen as a reference to aid reading the official specification. In case of any discrepancies between the two versions, the official version always takes precedence.

•Ordering Information

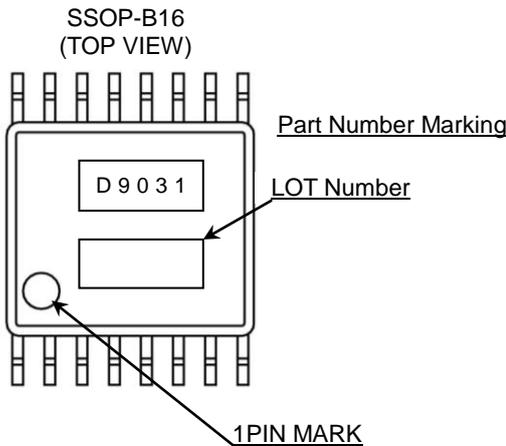


•Physical Dimension Tape and Reel Information

**SSOP-B16**



•Marking Diagram



•Revision History

Date	Revision	Changes
27/MAR/2012	001	Initial draft
05/NOV/2012	002	P.10 Change Timing chart and the explanation of detection time and release time P.11 Add the overvoltage protection (OVP) Timing chart and the under voltage protection (UVP) Timing chart
17/JUL/2014	003	P.16 Size expansion of the expression to set frequency

# Notice

## Precaution on using ROHM Products

1. If you intend to use our Products in devices requiring extremely high reliability (such as medical equipment <sup>(Note 1)</sup>, aircraft/spacecraft, nuclear power controllers, etc.) and whose malfunction or failure may cause loss of human life, bodily injury or serious damage to property ("Specific Applications"), please consult with the ROHM sales representative in advance. Unless otherwise agreed in writing by ROHM in advance, ROHM shall not be in any way responsible or liable for any damages, expenses or losses incurred by you or third parties arising from the use of any ROHM's Products for Specific Applications.

(Note1) Medical Equipment Classification of the Specific Applications

JAPAN	USA	EU	CHINA
CLASS III	CLASS III	CLASS II b	CLASS III
CLASS IV		CLASS III	

2. ROHM designs and manufactures its Products subject to strict quality control system. However, semiconductor products can fail or malfunction at a certain rate. Please be sure to implement, at your own responsibilities, adequate safety measures including but not limited to fail-safe design against the physical injury, damage to any property, which a failure or malfunction of our Products may cause. The following are examples of safety measures:
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  - [b] Installation of redundant circuits to reduce the impact of single or multiple circuit failure
3. Our Products are not designed under any special or extraordinary environments or conditions, as exemplified below. Accordingly, ROHM shall not be in any way responsible or liable for any damages, expenses or losses arising from the use of any ROHM's Products under any special or extraordinary environments or conditions. If you intend to use our Products under any special or extraordinary environments or conditions (as exemplified below), your independent verification and confirmation of product performance, reliability, etc, prior to use, must be necessary:
  - [a] Use of our Products in any types of liquid, including water, oils, chemicals, and organic solvents
  - [b] Use of our Products outdoors or in places where the Products are exposed to direct sunlight or dust
  - [c] Use of our Products in places where the Products are exposed to sea wind or corrosive gases, including Cl<sub>2</sub>, H<sub>2</sub>S, NH<sub>3</sub>, SO<sub>2</sub>, and NO<sub>2</sub>
  - [d] Use of our Products in places where the Products are exposed to static electricity or electromagnetic waves
  - [e] Use of our Products in proximity to heat-producing components, plastic cords, or other flammable items
  - [f] Sealing or coating our Products with resin or other coating materials
  - [g] Use of our Products without cleaning residue of flux (even if you use no-clean type fluxes, cleaning residue of flux is recommended); or Washing our Products by using water or water-soluble cleaning agents for cleaning residue after soldering
  - [h] Use of the Products in places subject to dew condensation
4. The Products are not subject to radiation-proof design.
5. Please verify and confirm characteristics of the final or mounted products in using the Products.
6. In particular, if a transient load (a large amount of load applied in a short period of time, such as pulse. is applied, confirmation of performance characteristics after on-board mounting is strongly recommended. Avoid applying power exceeding normal rated power; exceeding the power rating under steady-state loading condition may negatively affect product performance and reliability.
7. De-rate Power Dissipation (Pd) depending on Ambient temperature (Ta). When used in sealed area, confirm the actual ambient temperature.
8. Confirm that operation temperature is within the specified range described in the product specification.
9. ROHM shall not be in any way responsible or liable for failure induced under deviant condition from what is defined in this document.

## Precaution for Mounting / Circuit board design

1. When a highly active halogenous (chlorine, bromine, etc.) flux is used, the residue of flux may negatively affect product performance and reliability.
2. In principle, the reflow soldering method must be used; if flow soldering method is preferred, please consult with the ROHM representative in advance.

For details, please refer to ROHM Mounting specification

**Precautions Regarding Application Examples and External Circuits**

1. If change is made to the constant of an external circuit, please allow a sufficient margin considering variations of the characteristics of the Products and external components, including transient characteristics, as well as static characteristics.
2. You agree that application notes, reference designs, and associated data and information contained in this document are presented only as guidance for Products use. Therefore, in case you use such information, you are solely responsible for it and you must exercise your own independent verification and judgment in the use of such information contained in this document. ROHM shall not be in any way responsible or liable for any damages, expenses or losses incurred by you or third parties arising from the use of such information.

**Precaution for Electrostatic**

This Product is electrostatic sensitive product, which may be damaged due to electrostatic discharge. Please take proper caution in your manufacturing process and storage so that voltage exceeding the Products maximum rating will not be applied to Products. Please take special care under dry condition (e.g. Grounding of human body / equipment / solder iron, isolation from charged objects, setting of Ionizer, friction prevention and temperature / humidity control).

**Precaution for Storage / Transportation**

1. Product performance and soldered connections may deteriorate if the Products are stored in the places where:
  - [a] the Products are exposed to sea winds or corrosive gases, including Cl<sub>2</sub>, H<sub>2</sub>S, NH<sub>3</sub>, SO<sub>2</sub>, and NO<sub>2</sub>
  - [b] the temperature or humidity exceeds those recommended by ROHM
  - [c] the Products are exposed to direct sunshine or condensation
  - [d] the Products are exposed to high Electrostatic
2. Even under ROHM recommended storage condition, solderability of products out of recommended storage time period may be degraded. It is strongly recommended to confirm solderability before using Products of which storage time is exceeding the recommended storage time period.
3. Store / transport cartons in the correct direction, which is indicated on a carton with a symbol. Otherwise bent leads may occur due to excessive stress applied when dropping of a carton.
4. Use Products within the specified time after opening a humidity barrier bag. Baking is required before using Products of which storage time is exceeding the recommended storage time period.

**Precaution for Product Label**

QR code printed on ROHM Products label is for ROHM's internal use only.

**Precaution for Disposition**

When disposing Products please dispose them properly using an authorized industry waste company.

**Precaution for Foreign Exchange and Foreign Trade act**

Since our Products might fall under controlled goods prescribed by the applicable foreign exchange and foreign trade act, please consult with ROHM representative in case of export.

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